

Vcc

AOUT

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Data sheet acquired from Harris Semiconductor SCHS069D – Revised November 2004

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9208-39308

TERMINAL ASSIGNMENT

VDD

FOUT

SELECT

EOUT

FIN

EIN

CMOS Hex Voltage-Level Shifter for TTL-to-CMOS or CMOS-to-CMOS Operation

High-Voltage Types (20-Volt Rating)

Features:

- Independence of power-supply sequence considerations-V_{CC} can exceed V_{DD}; input signals can exceed both V_{CC} and V_{DD}
- Up and down level-shifting capability
- Shiftable input threshold for either CMOS or TTL compatibility
- Standardized symmetrical output characteristics
- 100% tested for quiescent current @ 20 V

CD4504B Types

- Maximum input current of 1 µA at 18 V over full package-temperature range; 100 nA at 18 V and 25° C
- 5 V, 10 V, and 15 V parametric ratings
- Meets all requirements of JEDEC Standard No. 13B, "Standard Specifications for Description of 'B' Series CMOS Devices"

CD4504B hex voltage level-shifter consists of six circuits which shift input signals from the V_{CC} logic level to the V_{DD} logic level. To shift TTL signals to CMOS logic levels, the SELECT input is at the V_{CC} HIGH logic state. When the SELECT input is at a LOW logic state, each circuit translates signals from one CMOS level to another.

The CD4504B types are supplied in 16-lead hermetic dual-in-line ceramic packages (F3A suffix), 16-lead dual-in-line plastic packages (E suffix), 16-lead small-outline packages (M, M96, and MT suffixes), and 16-lead thin shrink small-outline packages (PW and PWR suffixes).

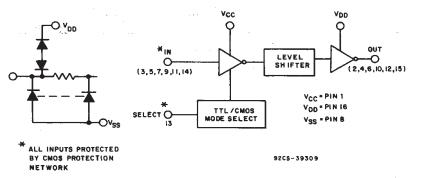


Fig. 1 - Functional diagram for CD4504B.

MAXIMUM RATINGS, Absolute-Maximum Values:	
DC SUPPLY-VOLTAGE RANGE, (VDD)	
Voltages referenced to VSS Terminal)	0.5V to +20V
INPUT VOLTAGE RANGE, ALL INPUTS	
DC INPUT CURRENT, ANY ONE INPUT	±10mA
POWER DISSIPATION PER PACKAGE (PD):	
For T _A = -55°C to +100°C	500mW
For T _A = +100°C to +125°C"	Derate Linearity at 12mW/°C to 200mW
DEVICE DISSIPATION PER OUTPUT TRANSISTOR	
FOR TA = FULL PACKAGE-TEMPERATURE RANGE (All Package Type	es)
OPERATING-TEMPERATURE RANGE (TA)	55°C to +125°C
STORAGE TEMPERATURE RANGE (Tstg)	85°C to +150°C
LEAD TEMPERATURE (DURING SOLDERING):	

STATIC ELECTRICAL CHARACTERISTICS

			CONDI	TIONS			I IMITE A	TINDICA	TED TEN	DEDATIO	DEC (Oct	 · 	T
CHARACTERISTIC		Vo	VIN	Vcc	V _{DD}		LIMITO	I INDICA	LIED IEN	PERATU	+25		1
		(V)	(V)	(V)	(V)	-55	-40	+85	+125	MIN	TYP	MAX	UNITS
Quiescent De		_	0, 5	5	5	1.5	1.5	1.5	1.5	_	0.02	1.5	
in CMOS-C	Max and ICC	_	0,10	5	10	2	2	2	2	_	0.02	2	mA
000	MOO MOO		0, 15	5	15	4	4	120	120	_	0.02	4	μА
	- 11 No. 1	_	0,20	5	20	20	20	600	600	_	0.04	20	1
	evice Current,		0, 5	5	5	5	5	6	6	_	2.5	5	
ICC Max TT	L-CMOS Mode	-	0, 10	5	10	5	5	6	6		2.5	5	1 mA
		_	0,15	5	15	5	5	6	6	_	2.5	5	
Output Low (Sink)		0.4	0.5	_	5	0.64	0.61	0.42	0.36	0.51	1	_	
Current, IOL	Min	0.5	0,10	_	10	1.6	1.5	1.1	0.9	1.3	2.6	_	1
		1.5	0, 15	- L	15.	4.2	4	2.8	2.4	3.4	6.8		1 .
Output High (Source)	•	4.6	0,5	_	5	-0.64	-0.61	-0.42	-0.36	-0.51	-1	_	l _{mA}
Current, IOH	_i Min	2.5	0,5	_	5	-2	-1.8	-1.3	-1.15	-1.6	-3.2	_	1
		9.5	0, 10	_	10	-1.6	-1.5	-1.1	-0.9	-1.3	-2.6	 	
		13.5	0,15	_	15	-4.2	-4	-2.8	-2.4	-3.4	-6.8		
Output Voltage:		 	0,5		5	0.05				_	0	0.05	1
Low-Level,	V _{OL} Max	_	0,10	_	10	0.05					0	0.05	1
		_	0,15	_	15	0.05					0	0.05	
Output Voltag	ge:	_	0,5	_	5	4.95				4.95	5	_	1
High-Level,	V _{OH} Min	_	0,10	_	10	9.95				9.95	10	_	
		_	0,15		15					14.95	15	_	
Input Low	TTL-CMOS	1	_	5	10		0.	8			_	0.8	
Voltage, V _{IL} Max	TTL-CMOS	1	_	5	15		0.	8		_		0.8	l v
Note 1	CMOS-CMOS	1	_	5	10		1.	5		_		1.5	1
	CMOS-CMOS	1.5	_	5	15		1.	5		_		1,5	1
	CMOS-CMOS	1.5	_	10	15		3				-	3	İ
Input High Voltage, VIH Min Note 1	TTL-CMOS	9	_	5	10	2				2	_		
	TTL-CMOS	13.5	_	5	15	2			2	_		1	
	CMOS-CMOS	9		5	10		3.5				_		1
	CMOS-CMOS	13.5	_	5	15		3.			3.5 3.5			1
	CMOS-CMOS	13.5	_	10	15		7			7	_	_	
Input Current,	lini Max	_	0,18		18	±0.1	±0.1	±1	±1	· -	±10 ⁻⁵	±0.1	μΑ

Note 1: Applies to the 6 input signals. For mode control (P13), only the CMOS-CMOS ratings apply.

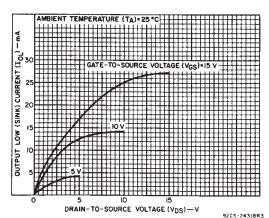


Fig. 2 - Typical output low (sink) current characteristics.

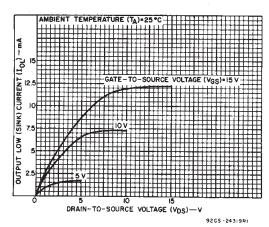
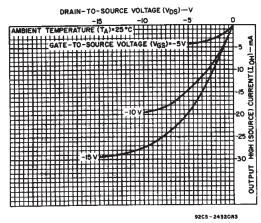


Fig. 3 - Minimum output low (sink) current characteristics.

CD4504B Types



DRAIN-TO-SOURCE VOLTAGE (VDS)—V

-15 -(0 -5 0)

AMBIENT TEMPERATURE (TA)=25°C

GATE-TO-SOURCE VOLTAGE (VGS)=-5 VI

-15 -(10 T)

-15 -(1

Fig. 4 - Typical output high (source) current characteristics.

Fig. 5 - Minimum output high (source) current characteristics.

RECOMMENDED OPERATING CONDITIONS

For maximum reliability, nominal operating conditions should be selected so that operation is always within the following ranges:

CHARACTERISTIC	VDD	LIM	UNITS	
OHANAO I ENISTIO	(V)	Min.	Max.	UNITS
Supply-Voltage Range (For T _A = Full Package-Temperature Range)	_	5	18	V

DYNAMIC ELECTRICAL CHARACTERISTICS, At TA = 25°C; Input tr,tf = 20 ns, CL = 50 pF, RL = 200 Ω

CHARACTERISTIC		SHIFTING MODE	VCC (V)	VDD (V)	LIMITS		UNITS
CHARACTERISTI		SHIFTING MODE	VCC (V)	ADD (A)	TYP.	MAX.	
		TTL to CMOS	5	10	140	280	
		V _{DD} > V _{CC}	5	15	140	280	
Propagation Delay:	ſ	CMOS to CMOS	5	10	120	240	
High-to Low,	t _{PHL}	$V_{DD} > V_{CC}$	5	15	120	240	
			10	15	70	140	
	Ţ	CMOS to CMOS	10	5	275	550	1
		$V_{CC} > V_{DD}$	15	5	275	550	
			15	10	70	140	
		TTL to CMOS	5	10	140	280	ns
	1	V _{DD} > V _{CC}	5	15	140	280	
		CMOS to CMOS	5	10	120	240]
Low-to-High,	t _{PLH}	$V_{DD} > V_{CC}$	5	15	120	240	
		<u></u>	10	15	70	140	
		CMOS to CMOS	10	5	200	400	
	2.5	Vcc > Vpp	15	5	200	400	
			15	10	60	120	
				5	100	200	
Transition Time,	t _{THL} ,t _{TLH}	All Modes		10	50	100	
				15	40	80	
Input Capacitance,	Cin	Any Input			5	7.5	pF

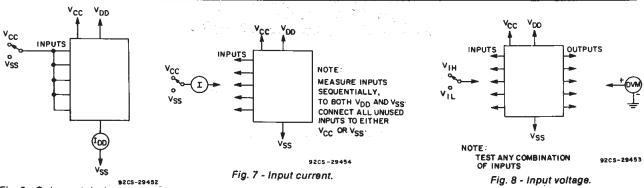


Fig. 6 - Quiescent device current.

CD4504B Types

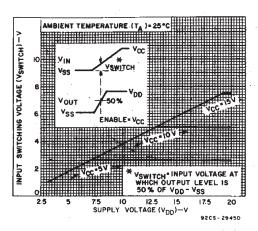


Fig. 9 - Typical input switching as a function of high-level supply voltage.
(SELECT at Vcc-CMOS mode).

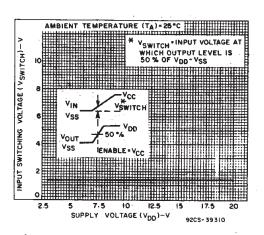


Fig. 10 - Typical input switching as a function of high-level supply voltage (SELECT at Vss-TTL mode).

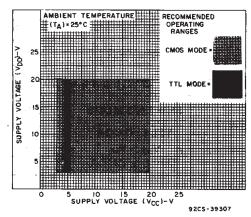
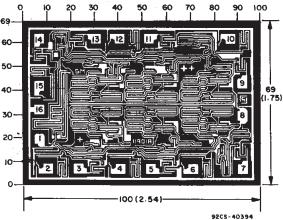


Fig. 11 - High-level supply voltage vs. low-level supply voltage.



Dimensions in parentheses are in millimeters and are derived from the basic inch dimensions as indicated. Grid graduations are in mils (10^{-3} inch).

Dimensions and pad layout for CD4504BH.





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PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
CD4504BE	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4504BEE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type
CD4504BF3A	ACTIVE	CDIP	J	16	1	TBD	Call TI	N / A for Pkg Type
CD4504BM	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4504BM96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4504BM96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4504BME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4504BMT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4504BMTE4	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4504BPW	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4504BPWE4	ACTIVE	TSSOP	PW	16	90	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4504BPWR	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
CD4504BPWRE4	ACTIVE	TSSOP	PW	16	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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PACKAGE OPTION ADDENDUM

12-Jan-2006

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14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



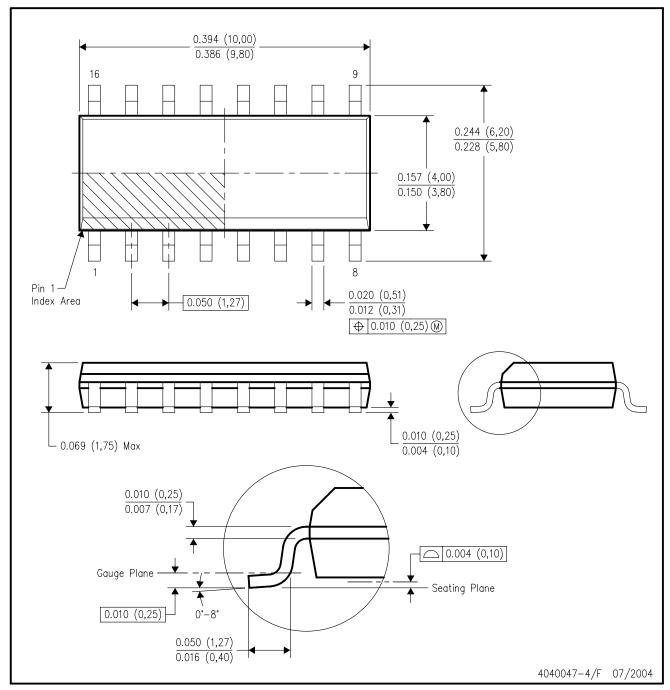
NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-012 variation AC.



PW (R-PDSO-G**)

14 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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